

SKiIP 312 GDL 120 - 404 WT (E/U)

Absolute Maximum Ratings		Values	Units
Symbol	Conditions ¹⁾		
IGBT & Inverse Diode			
V_{CES}	Operating DC link voltage	1200	V
V_{CC} ¹⁰⁾		900	V
I_C	$T_{heatsink} = 25\text{ °C}$	300	A
I_{CM}	$T_{heatsink} = 25\text{ °C}; t_p < 1\text{ ms}$	600	A
T_j ³⁾	IGBT & Diode	-55 ... +150	°C
V_{isol} ⁴⁾	AC, 1 min.	3000 ⁵⁾	V
I_F	$T_{heatsink} = 25\text{ °C}$	240	A
I_{FM}	$T_{heatsink} = 25\text{ °C}; t_p < 1\text{ ms}$	600	A
I_{FSM}	$t_p = 10\text{ ms}; \sin.; T_j = 150\text{ °C}$	2160	A
I^2t (Diode)	$t_p = 10\text{ ms}; T_j = 150\text{ °C}$	23,4	KA ² s
Driver - inverter			
V_{S1}	Stabilized power supply	18	V
V_{S2} ¹⁰⁾	Nonstabilized power supply	30	V
dv/dt	Primary to second. side	75	KV/ μ s
T_{op}, T_{stg}	Operating / stor. temperature	-25 ... +85	°C

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
$V_{(BR)CES}$	Driver without power supply	$\geq V_{CES}$	-	-	V
I_{CES}	$V_{GE} = 0$ } $T_j = 25\text{ °C}$ $V_{CE} = V_{CES}$ } $T_j = 125\text{ °C}$	-	0,3	-	mA
V_{CEsat} ⁸⁾	$I_C = 225\text{ A}$ } $T_j = 25\text{ (125) °C}$ $I_C = 300\text{ A}$ } $T_j = 25\text{ (125) °C}$	-	2,75 (3,6)	-	V
V_{CEsat} ⁸⁾	$I_C = 300\text{ A}$ } $T_j = 25\text{ (125) °C}$	-	3,15 (4,2)	-	V
$I_{CETRIIP}$	$T_j = 125\text{ °C}; V_s = 15\text{ V} \pm 0,6\text{V}$	≥ 375	-	-	A
C_{CHC}	per SKiIPPACK AC side	-	0,8	-	nF
L_{CE}	Top (Bottom)	-	15	-	nH
$t_{d(on)}$	$V_{CC} = 600\text{ V}$ $I_C = 300\text{ A}$ $T_j = 125\text{ °C}$ inductive load	-	150	-	ns
$t_{d(on)Driver}$		-	1,2	-	μ s
t_r		-	100	-	ns
$t_{d(off)}$		-	0,7	-	μ s
$t_{d(off)Driver}$		-	1,2	-	μ s
t_f		-	80	-	ns
$E_{on} + E_{off}$		-	90	-	mJ
Inverse Diode ²⁾ - inverter					
$V_F^{8)} = V_{EC}$	$I_F = 225\text{ A}$ } $T_j = 25\text{ (125) °C}$ $I_F = 300\text{ A}$ } $T_j = 25\text{ (125) °C}$	-	2,0(1,8)	-	V
		-	2,25(2,05)	-	V
V_{TO}	$T_j = 125\text{ °C}$	-	1,0	-	V
r_T	$T_j = 125\text{ °C}$	-	4,0	-	m Ω
$E_{on} + E_{off}$	$I_F = 300\text{ A}; T_j = 125\text{ °C}$	-	12	-	mJ
Diode ²⁾ - brake chopper (BC)					
$V_F^{8)} = V_{EC}$	$I_F = 150\text{ A}$ } $T_j = 25\text{ (125) °C}$ $I_F = 200\text{ A}$ } $T_j = 25\text{ (125) °C}$	-	2,0(1,8)	-	V
		-	2,25(2,05)	-	V
V_{TO}	$T_j = 125\text{ °C}$	-	1,0	-	V
r_T	$T_j = 125\text{ °C}$	-	6,0	-	m Ω
Thermal Characteristics					
R_{thjh}	per IGBT	-	0,08	-	K/W
R_{thjh}	per diode inverter (BC)	-	0,27(0,4)	-	K/W
T_{tp} ¹¹⁾	Over temperature protection	109	115	121	°C
R_{thha} ⁶⁾	P16/360 F; $v_{air} = 297\text{ m}^3/\text{h}$	-	0,036	-	K/W
Mechanical Data					
M_{dc}	for DC terminals, SI Units	4	-	6	Nm
M_{ac}	for AC terminals, SI Units	8	-	10	Nm
Case			S5		

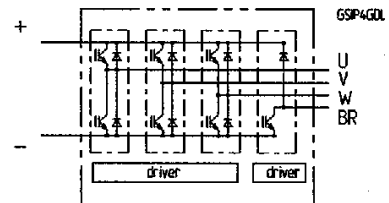
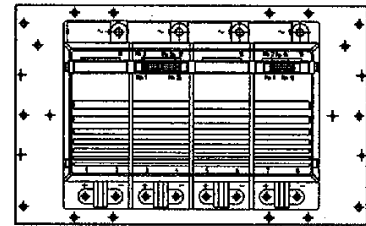
SKiIPPACK®

SK integrated intelligent Power PACK

3-phase bridge with brake chopper

SKiIP 312 GDL 120 + Driver 404 WT (E/U) ⁷⁾

Case S5



Features

- Low thermal impedance
- Optimal thermal management with integrated heatsink
- Pressure contact technology with increased power cycling capability, compact design
- Low stray inductance
- High power, small losses
- Overtemp. protection
- Short circuit protection
- Isolated power supply

¹⁾ $T_{heatsink} = 25\text{ °C}$, unless otherwise specified

²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast)

³⁾ without driver

⁴⁾ Driver input to DC link/AC output or DC link/AC output to heatsink 3,5 kV (AC; on request)

⁵⁾ other heatsink on request

⁶⁾ Driver wire input

⁷⁾ T - Temperature protection

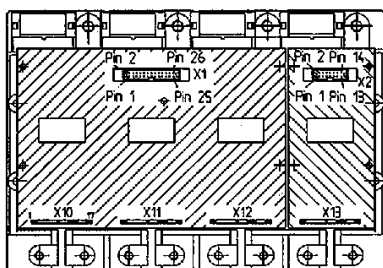
⁸⁾ E/U-voltage levels V_{DC} br. chopper

⁹⁾ Chip voltage drop

¹⁰⁾ 24 V supply voltage selective with SK-DC link (low inductance)

¹¹⁾ thermal reference for R_{thjh} ; R_{thha}

SKiPPACK®
SK integrated
intelligent Power PACK
3-phase bridge with
brake chopper
SKiP 312 GDL 120
+ Driver 404 WT (E/U)³⁾



SKiP 312 GDL 120 - 404 WT (E/U)
Driver for 3-phase bridge and brake chopper

Absolute Maximum Ratings		3-phase bridge	brake chopper	Units	remark
Symbol	Conditions	Values			
V _{S1}	supply voltage primary	18		V	
V _{S2} ¹⁾	supply voltage primary	30		V	
I _{outmax}	output peak current max.	± 10	± 1,5	A	
I _{outAV}	output average current	± 50	± 90	mA	
f _{swmax}	switching frequency max.	12	5	kHz	
V _{CE}	collector emitter voltage sense across IGBT	1200		V	
dv/dt	rate of rise and fall of voltage (secondary to primary side)	75	50	kV/μs	
V _{isol IO} ⁴⁾	Isol. test volt. IN/OUT (RMS; 1 min)	2,5		kV~	
V _{isol 12}	Isol. test volt. OUT1 - OUT2	1,5		kV=	
T _{op} , T _{stg}	operating / stor. temperature	-25...+85		°C	

Characteristics		Values	Units	remark	
Symbol	Conditions				
V _{S1}	supply voltage primary	15,0 ±4%	V		
V _{S2} ¹⁾	supply voltage primary	24,0	V	+25%/-15%	
V _{uvs}	supply undervolt. monitoring	13	V		
V _{uvs} ¹⁾	supply undervolt. monitoring	19,5	16	V	
I _{S01}	sup. current pr.side (standby)	380	67	mA	
I _{S02} ¹⁾	sup. current pr.side (standby)	300	67	mA	
I _{S1}	sup. current pr.side (max)	900	77	mA	
I _{S2} ¹⁾	sup. current pr.side (max)	700	77	mA	
V _{IT+}	input thresh. volt. (high) min	12,9		V	
V _{IT-}	input thresh. volt. (low) max.	2,1		V	
V _{GE(on)}	turn-on output gate voltage	15	15	V	
V _{GE(off)}	turn-off output gate voltage	- 8	0	V	
t _{d(on)}	propagation delay time on	1,2	< 20	μs	typ.
t _{d(off)}	propagation delay time off	1,2	< 25	μs	typ.
t _{TD}	dead time of interlock	3		μs	typ.
V _{CEstat}	V _{CE} -thresh. st. monitoring	5,1	5	V	typ.
V _{CEdyn}	V _{CE} -thresh. dyn. monitoring	9,5	10	V	typ.
V _{ol} ²⁾	logic low output voltage	< 0,5		V	15mA sink 2,5mA sink
V _{oH} ²⁾	logic high output voltage	max.30		V	
V _{RESET L}	Input voltage RESET Low		< 2	V	
V _{RESET H}	Input voltage RESET High		> 12	V	
V _{IL}	logic low input volt. Chop. ext. ON		< 5	V	> 5 mA
V _{IH}	logic high input volt. Chop.ext. ON		> 11,5	V	< 1 mA
t _{pdon-error}	propag. delay time-on error	6	< 60	μs	
t _{p RESET}	min. pulse width error memory RESET	5		μs	
T _{err}	max. temperature	115 ± 6		°C	
I _{AOmax}	max. output current	± 5		mA	pin 20

Voltage levels V _{DCbrake} ⁵⁾		Values	Units	remark	
Symbol	Conditions				
V _{DCmax}	DC-link voltage (max)		730	V	E
			860	V	U
V _{DCON}	Chopper voltage ON		681	V	E
			802	V	U
V _{DCOFF}	Chopper voltage OFF		667	V	E
			786	V	U

Features

3-phase bridge

- CMOS compatible inputs
- Short circuit protection by V_{CE} monitoring and soft switch off
- Drive interlock top/bottom
- Isolation by transformers
- Supply undervoltage protection
- Overtemperature protection

Features

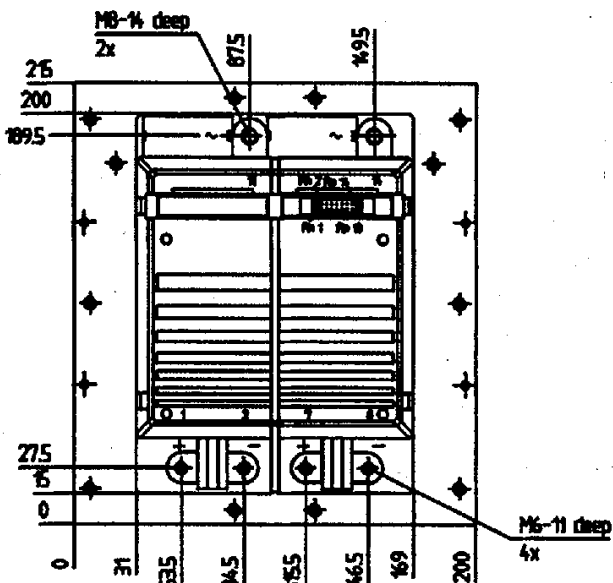
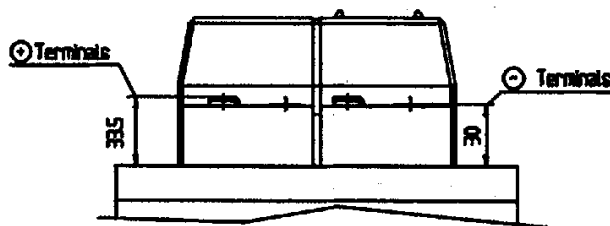
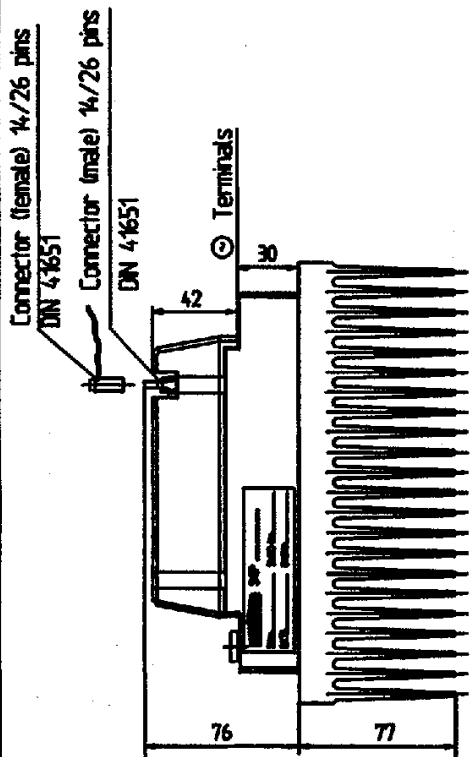
brake chopper

- Short circuit protection by V_{CE} monitoring and soft switch off
- Self controlled switching
- Supply undervoltage protection
- Overtemperature protection

1) 24 V - supply voltage selective
 2) Open collector output external pull-up resistor necessary
 3) W - Driver wire input
 T - Temperature protection
 E/U-voltage levels V_{DC} br. chopper
 E - EUROPE (400 V_{RMS})
 U - USA (460 V_{RMS})
 4) 3,5 kV_{AC} (on request)
 5) other levels (on request)

Case S2
 SKIIPACK
 View from right

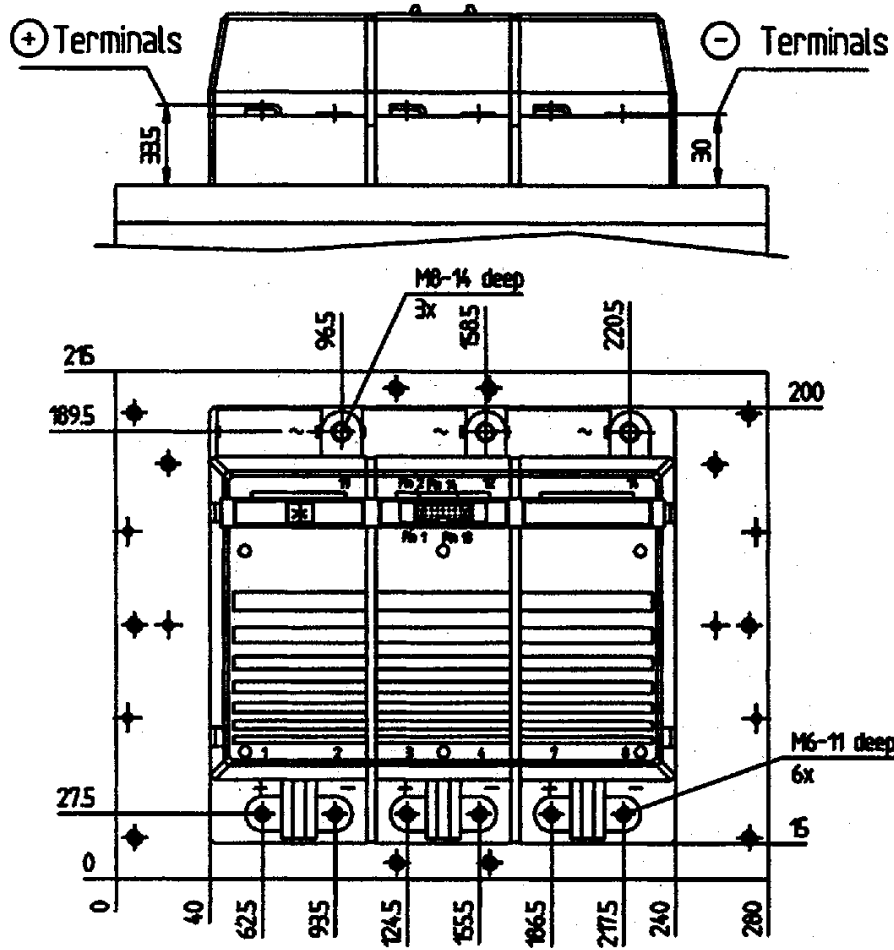
SKIIPACK 2 - GB



Case S3

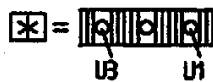
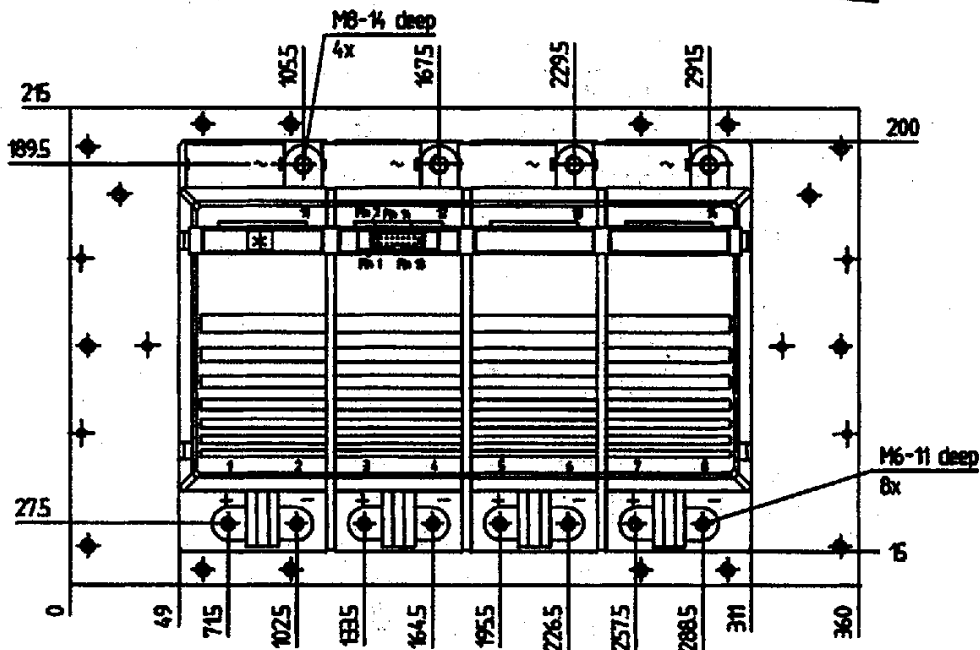
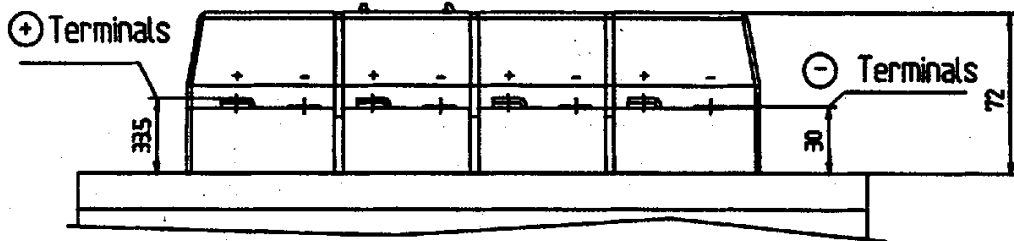
SKIIPACK 3 - GB, GD

CASES3



Version SKiiP ... GB ... FT (Fibreoptic input)

CASES4

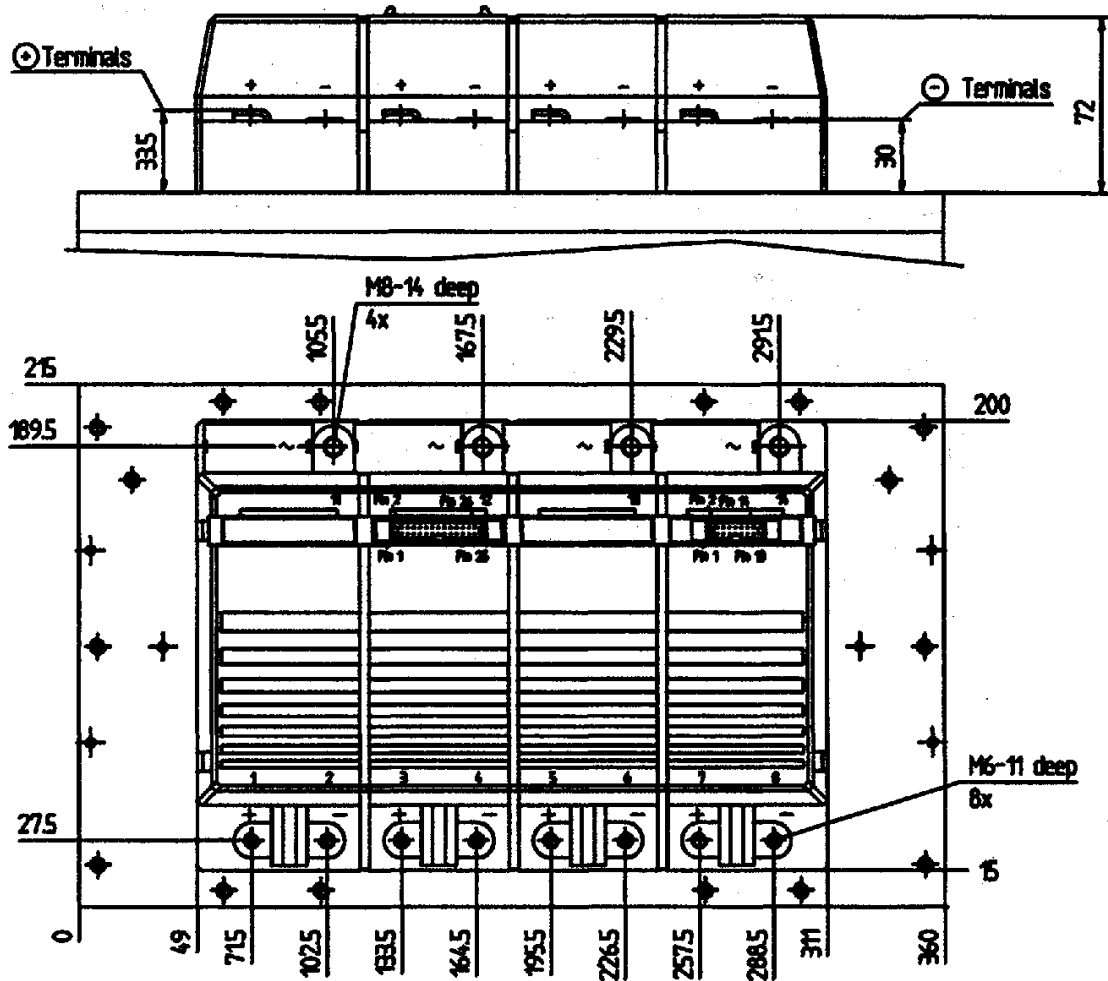


Version SKiIP ... GB ... FT (Fibreoptic input)

Case S5

SKIIPACK 4 - GDL

CASES5



SKIIPACK view from right

